# 42nd RD50 Workshop on Radiation Hard Semiconductor Devices for Very High Luminosity Colliders (Montenegro)

## Wednesday, 21 June 2023

#### **LGAD** - Conference Hall (11:40 - 16:20)

-Conveners: Valentina Sola; Roberta Arcidiacono

time	[id] title	presenter
11:40	[5] Preparations for LGAD characterization with 30 MeV protons	KRIZEK, Filip
12:00	[1] Gain degradation study after neutron and proton irradiations in Low Gain Avalanche Diodes	ZAREEF, Fasih
12:20	Lunch break	
13:50	[37] First measurements of irradiated CNM LGADs with carbon enriched gain layer	HOWARD, Alissa Shirley-Ann HITI, Bojan KRAMBERGER, Gregor
14:10	[8] Correlation between leakage current and charge gain in irradiated LGADs	KRAMBERGER, Gregor
14:30	[61] Fast QA tests for LGADs	KRAMBERGER, Gregor
14:50	[6] Measurements of the RSD performance at a test beam (DESY)	CARTIGLIA, Nicolo
15:10	[27] Characterisation of the EXFLU1 batch from FBK	SOLA, Valentina
15:30	[10] Deep-Junction LGAD and adaptive gain layer RD50 proposal	Dr MAZZA, Simone Michele
15:50	[57] Discussion: LGAD 1	Dr PELLEGRINI, Giulio KRAMBERGER, Gregor

## Thursday, 22 June 2023

### **LGAD** - Conference Hall (09:00 - 12:40)

-Conveners: Nicolo Cartiglia; Gianluigi Casse

time	[id] title	presenter
09:00	[15] Investigating the effect of processing and isolation layout design parameters of IP region with 2 p-stops and bias ring on charge collection and hole amplification in IP region: Case studies on Type 10 from Ti-LGAD batch (W11) and UFSD 4.0 (W18)	LASTOVICKA MEDIN, Gordana BOZOVIC, Ivona DOKNIC, Jovana
09:20	[34] Characterization of W7 Type 10 and W7 Type 4 and comparison to W11 Type 10 LGAD prototypes	Prof. LASTOVICKA-MEDIN, Gordana DOKNIC, Jovana BACKOVIC, Vanja
09:40	[14] Radiation-Induced Bulk Defects and their Impact on the Charge Multiplication in Inter-Pad region in TI-LGADs: A Comparative Study between Irradiated and Non-Irradiated LGAD Samples with Two Trenches i	LASTOVICKA MEDIN, Gordana BOZOVIC, Ivona DOKNIC, Jovana BACKOVIC, Vanja
10:00	[23] Electrical characterization and attenuation factor determination of AC-LGAD run at CNM	MANOJLOVIC, Milos
10:20	[9] Simulation of Landau fluctuations on timing performance of LGADs	DEBEVC, Jernej
10:40	Coffee Break	
11:10	[30] RD50 Project proposal: Partial Activation of Boron to enhance the radiation tolerance of the gain implant – PAB	SOLA, Valentina
11:30	[46] Discussion: LGAD 2	Dr PELLEGRINI, Giulio KRAMBERGER, Gregor CARTIGLIA, Nicolo